NSN 5961-01-149-6917

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-149-6917 **Inclosure Material:** Metal **Overall Length:** 1.453 inches **Overall Diameter:** 0.667 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Overall Width Across Flats:** 0.677 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 nonrepetitive peak reverse voltage, peak total value and 100.0 repetitive peak reverse voltage, peak total value **Current Rating Per Characteristic:** 600.00 amperes forward current, average preset and 50.00 amperes forward current, average absolute **Test Data Document:** 27963-85946500 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No